PBSS4140T

40 V, 1 A NPN low VCEsat (BISS) transistor

1 April 2023

Product data sheet

1. General description

NPN low V_{CEsat} transistor in a small SOT23 plastic package. PNP complement: PBSS5140T.

2. Features and benefits

- Low collector-emitter saturation voltage
- High current capabilities
- Improved device reliability due to reduced heat generation

3. Applications

- · General purpose switching and muting
- LCD backlighting
- Supply line switching circuits
- · Battery driven equipment (mobile phones, video cameras and hand-held devices).

4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{CEO}	collector-emitter voltage	open base	-	-	40	V
I _{CM}	peak collector current	single pulse; t _p ≤ 1 ms	-	-	2	Α
R _{CEsat}	collector-emitter saturation resistance	I_C = 500 mA; I_B = 50 mA; pulsed; $t_p \le$ 300 μs; $\delta \le 0.02$; T_{amb} = 25 °C	-	260	500	mΩ

5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	В	base	3	С
2	Е	emitter		j
3	С	collector		В —
			SOT23	 E sym123



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6. Ordering information

Table 3. Ordering information

Type number	Package				
	Name	Description	Version		
PBSS4140T		plastic, surface-mounted package; 3 terminals; 1.9 mm pitch; 2.9 mm x 1.3 mm x 1 mm body	SOT23		

7. Marking

Table 4. Marking codes

Type number	Marking code[1]
PBSS4140T	ZT%

[1] % = placeholder for manufacturing site code

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V_{CBO}	collector-base voltage	open emitter		-	40	V
V_{CEO}	collector-emitter voltage	open base		-	40	V
V_{EBO}	emitter-base voltage	open collector		-	5	V
I _C	collector current			-	1	Α
I _{CM}	peak collector current	single pulse; t _p ≤ 1 ms		-	2	Α
I _{BM}	peak base current			-	1	mA
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C	[1]	-	300	mW
			[2]	-	450	mW
Tj	junction temperature			-	150	°C
T _{amb}	ambient temperature			-65	150	°C
T _{stg}	storage temperature			-65	150	°C

^[1] Device mounted on an FR4 PCB, single-sided, 35 µm copper, tin-plated and standard footprint.

9. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
$R_{th(j-a)}$	thermal resistance from	in free air	[1]	-	-	417	K/W
	junction to ambient		[2]	-	-	278	K/W

^{1]} Device mounted on an FR4 PCB, single-sided, 35 μm copper, tin-plated and standard footprint.

^[2] Device mounted on an FR4 PCB, single-sided, 35 μm copper, tin-plated, mounting pad for collector 1 cm².

^[2] Device mounted on an FR4 PCB, single-sided, 35 μm copper, tin-plated, mounting pad for collector 1 cm².

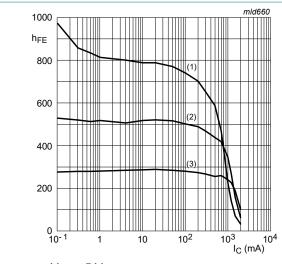
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10. Characteristics

Table 7. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$V_{(BR)CBO}$	collector-base breakdown voltage	$I_C = 100 \ \mu A; I_E = 0 \ A; T_{amb} = 25 \ ^{\circ}C$	40	-	-	V
V _{(BR)CEO}	collector-emitter breakdown voltage	$I_C = 2 \text{ mA}; I_B = 0 \text{ A}; T_{amb} = 25 \text{ °C}$	40	-	-	V
V _{(BR)EBO}	emitter-base breakdown voltage (collector open)	$I_E = 100 \ \mu A; I_C = 0 \ A; T_{amb} = 25 \ ^{\circ}C$	5	-	-	V
I _{CBO}	collector-base cut-off	V _{CB} = 40 V; I _E = 0 A; T _{amb} = 25 °C	-	-	100	nA
	current	V _{CB} = 40 V; I _E = 0 A; T _{amb} = 150 °C	-	-	50	μΑ
I _{CEO}	collector-emitter cut-off current (base open)	I _B = 0 A; V _{CE} = 30 V; T _{amb} = 25 °C	-	-	100	nA
I _{EBO}	emitter-base cut-off current	V _{EB} = 5 V; I _C = 0 A; T _{amb} = 25 °C	-	-	100	nA
I _{CES}	collector-emitter cut-off current	V _{CE} = 30 V; T _{amb} = 25 °C	-	-	100	nA
h _{FE}	DC current gain	V _{CE} = 5 V; I _C = 1 mA; T _{amb} = 25 °C	300	-	-	
		V _{CE} = 5 V; I _C = 500 mA; T _{amb} = 25 °C	300	-	900	
		V _{CE} = 5 V; I _C = 1 A; T _{amb} = 25 °C	200	-	-	
V _{CEsat}	collector-emitter	I _C = 100 mA; I _B = 1 mA; T _{amb} = 25 °C	-	-	200	mV
	saturation voltage	I _C = 500 mA; I _B = 50 mA; T _{amb} = 25 °C	-	-	250	mV
		I _C = 1 A; I _B = 100 mA; T _{amb} = 25 °C	-	-	500	mV
R _{CEsat}	collector-emitter saturation resistance	I_C = 500 mA; I_B = 50 mA; pulsed; t_p ≤ 300 μs; δ ≤ 0.02; T_{amb} = 25 °C	-	260	500	mΩ
V _{BEsat}	base-emitter saturation voltage	I _C = 1 A; I _B = 100 mA; T _{amb} = 25 °C	-	-	1.2	V
V_{BEon}	base-emitter turn-on voltage	V _{CE} = 5 V; I _C = 1 A; T _{amb} = 25 °C	-	-	1.1	V
f _T	transition frequency	V_{CE} = 10 V; I_{C} = 50 mA; f = 100 MHz; T_{amb} = 25 °C	150	-	-	MHz
C _c	collector capacitance	$V_{CB} = 10 \text{ V}; I_E = 0 \text{ A}; i_e = 0 \text{ A}; f = 1 \text{ MHz}; $ $T_{amb} = 25 ^{\circ}\text{C}$	-	-	10	pF

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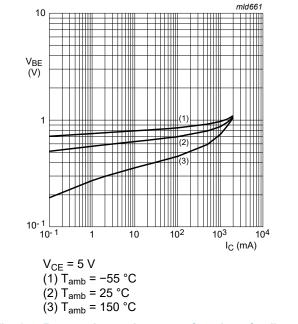


$$V_{CE} = 5 V$$

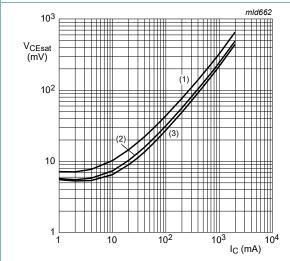
$$(1) T_{amb} = 150 °$$

(3)
$$T_{amb} = -55 \, ^{\circ}C$$

Fig. 1. DC current gain as a function of collector current; typical values



Base-emitter voltage as a function of collector Fig. 2. current; typical values



$$I_C/I_B = 10$$

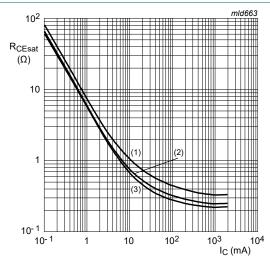
(1)
$$T_{amb} = 150 \, ^{\circ}C$$

$$(2) T_{amb} = 25 °C$$

(2)
$$T_{amb} = 25 \text{ °C}$$

(3) $T_{amb} = -55 \text{ °C}$

Fig. 3. Collector-emitter saturation voltage as a function of collector current; typical values



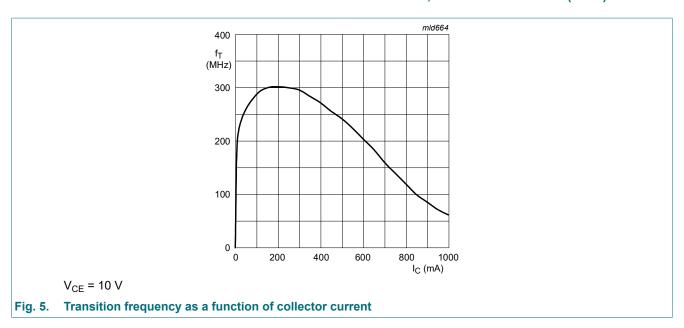
$$I_C/I_B = 10$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

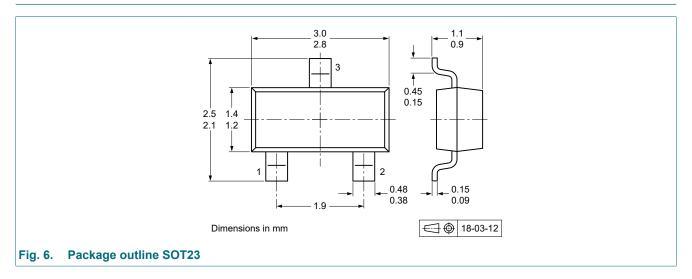
$$(3) T_{amb} = -55 °C$$

Equivalent on-resistance as a function of Fig. 4. collector current; typical values

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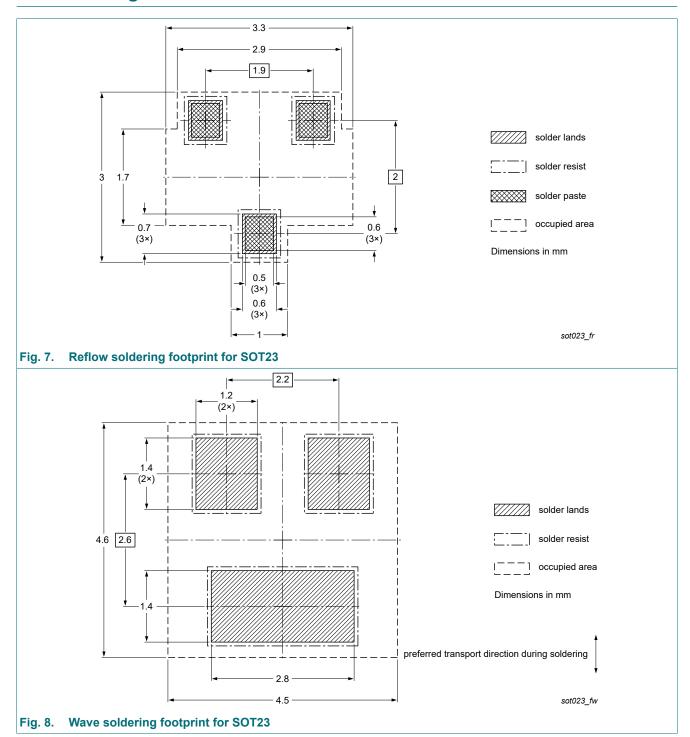


11. Package outline



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12. Soldering



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13. Revision history

Table 8. Revision history

Data sheet ID	Release date	Data sheet status	Change notice	Supersedes		
PBSS4140T v.3	20230401	Product data sheet	-	PBSS4140T v.2		
Modifications:	 The format of this data sheet has been redesigned to comply with the identity guidelines of Nexperia. Legal texts have been adapted to the new company name where appropriate. Product changed to non automotive. Please refer to the automotive product(s) with -Q. 					
PBSS4140T v.2	20050224	Product data sheet	-	PBSS4140T v.1		
PBSS4140T v.1	20050214	Product specification	-	-		

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14. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
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